

LC7537N, 7537AN

SANYO SEMICONDUCTOR CORP

3025B

3052A

CMOS LSI

Electronic Volume Control System for Audio Equipment

©2169A

Functions

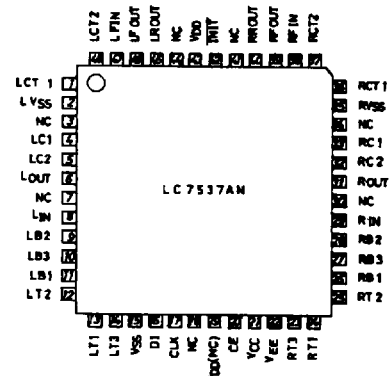
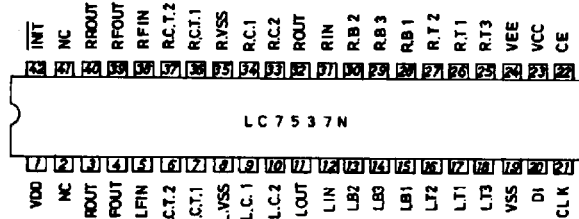
The LC7537N is an electronic control LSI capable of electronically controlling the volume, balance, loudness, fader, bass, and treble functions individually with fewer externally connected component parts.

Features

- Enables controlling the below-listed functions with 3-line serial data, including CE, DI, and CLK. Also, due to 0V to 5V swing of the serial data input voltage, permits the use of a general purpose microcomputer.
- (1) Volume : Separately controls the Lch and Rch volume levels across 81 positions over the 0dB to -79dB (in 1dB steps) range and $-\infty$, and consequently also serves balance control purposes.
- (2) Loudness : By virtue of a center tap provided at the -20dB position of the volume controlling ladder resistors, permits loudness to be controlled with externally connected CR components.
- (3) Fader : By varying only the rear or front output level across 16 positions, provides fader functions (in 2dB steps over the 0dB to -20dB range, and 5dB steps over the -20dB to -45dB range, and at $-\infty$, for a total of 16 positions).

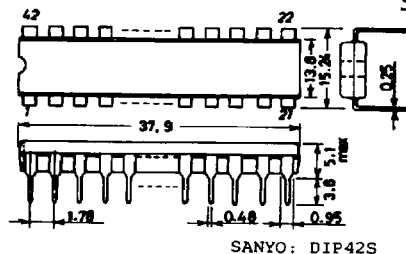
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Pin Assignment



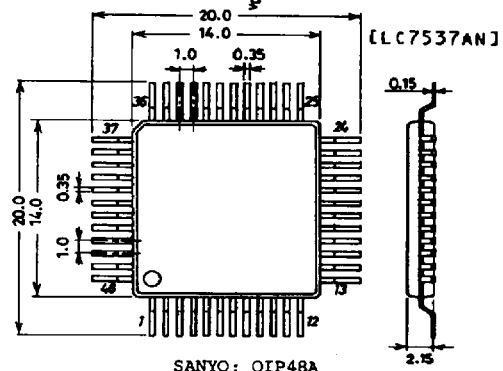
Case Outline 3025B
(unit:mm)

[LC7537N]



SANYO: DIP42S

Case Outline 3052A
(unit:mm)



SANYO: QIP48A

7018YT/6186KI, TS No. 2169-1/11

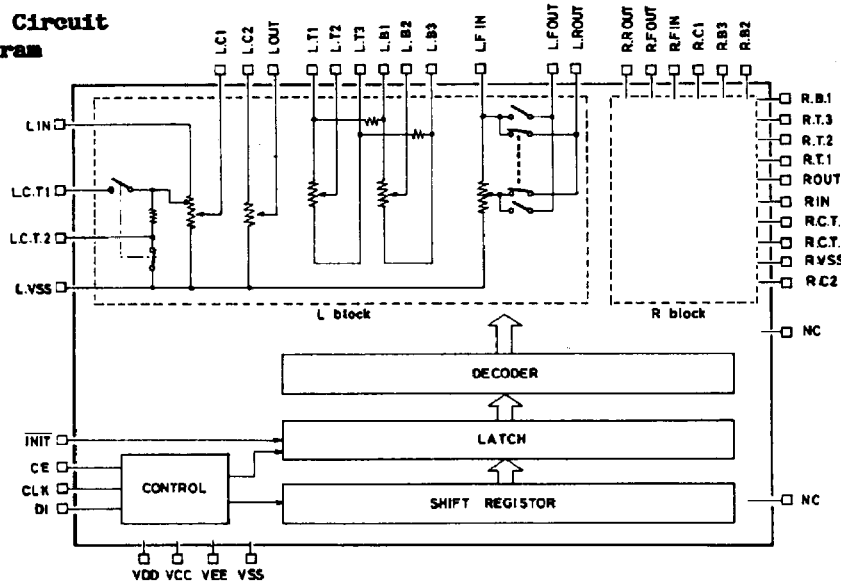
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- (4) Bass/Treble: With CR components externally connected, forms an NF type tone control circuit (Baxandall type) to exercise control across 15 positions over both the bass and treble functions in 2dB steps.

By virtue of its CMOS structure, the LSI operates under a broad power supply voltage range from +4.5V to +15V, permitting the use of either a single or a dual \pm power supply, whichever is preferred.

**Equivalent Circuit
Block Diagram**



Absolute Maximum Ratings at $T_a=25^\circ\text{C}$, $V_{SS}=0\text{V}$, $V_{DD}\geq V_{CC}>V_{SS}\geq V_{EE}$				unit
Maximum Supply Voltage	$V_{DD}-V_{EE}^{\text{max}}$	$V_{DD}, V_{EE}: V_{EE}\leq -8\text{V}$	16	V
	V_{CC}^{max}	$V_{CC}: V_{DD}\geq V_{CC}$	$V_{SS}-0.3$ to $V_{SS}+7$	V
Input Supply Voltage	V_{I1}	DI, CLK, CE	$V_{SS}-0.3$ to $V_{DD}+0.3$	V
	V_{I2}	INIT	$V_{EE}-0.3$ to $V_{DD}+0.3$	V
Allowable Power Dissipation	P_{dmax}	$T_a\geq 85^\circ\text{C}$	200	mW
Operating Temperature	T_{opg}		-40 to +85	$^\circ\text{C}$
Storage Temperature	$T_{stg}\#3$		-50 to +125	$^\circ\text{C}$

Allowable Operating Conditions at $T_a=25^\circ\text{C}$, $V_{SS}=0\text{V}$, $V_{DD}\geq V_{CC}>V_{SS}\geq V_{EE}$				unit
Supply Voltage #1	$V_{DD}-V_{EE}$	$V_{EE}\geq -7.5\text{V}$	4.5 to 15	V
	V_{CC}		4.5 to 5.5	V
Input "H"-Level Voltage	$V_{IH1}\#2$	DI, CLK, CE	$0.8V_{CC}$ to V_{DD}	V
	V_{IH2}	INIT	$0.8(V_{DD}-V_{EE})+V_{EE}$ to V_{DD}	V
Input "L"-Level Voltage	$V_{IL1}\#2$	DI, CLK, CE	V_{SS} to $0.2V_{CC}$	V
	V_{IL2}	INIT	V_{EE} to $0.2(V_{DD}-V_{EE})+V_{EE}$	V
Input Signal Amplitude	V_{IN}		V_{EE} to V_{DD}	Vp-p
Input Pulse Width	t_{pw}		1 min.	us
Setup Time	$t_{set up}$		1 min.	us
Hold Time	t_{hold}		1 min.	us
Operating Frequency	f_{opg}		up to 330	kHz
#1 : A 1,000pF or larger capacitor should be added on between each individual power supply terminal and V_{SS} .				
#2 : When the microcomputer side control signals rise faster than V_{DD} for the LC7537N, a 2kohm or higher resistor should be inserted midway on each of the DI, CLK, and CE lines.				
#3 : When mounting the QIP package on the board, do not dip the entire package in solder.				

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Electrical Characteristics at $T_a=25^{\circ}\text{C}$, $V_{DD}=+7.5\text{V}$, $V_{EE}=-7.5\text{V}$, $V_{CC}=+5\text{V}$

			min	typ	max	unit
Total Harmonic Distortion	THD(1)	$V_{IN}=1\text{V}$, $f=1\text{kHz}$, all flat overall		0.005	0.01	%
	THD(2)	$V_{IN}=1\text{V}$, $f=20\text{kHz}$, all flat overall		0.006	0.02	%
Crosstalk	CT	$V_{IN}=1\text{V}$, $f=1\text{kHz}$, all flat, $R_g=1\text{k}\Omega$	60	95		dB
Maximum Attenuation	Vomin(1)	$V_{IN}=1\text{V}$, $f=1\text{kHz}$, MAIN, $V_R=\infty$, FADER $V_R=\infty$	80	90		dB
Output	Vomin(2)	$V_{IN}=1\text{V}$, $f=1\text{kHz}$, MAIN $V_R=\infty$, $V_{DD}=8\text{V}$, FADER $V_R=\infty$, $V_{EE}=V_{SS}=0\text{V}$, C between V_{SS} and GND of $L/R=1000\mu\text{F}$	70	80		dB
VR Resistance Value	RVOL(1)	5dB-step	12	20	28	kohm
	RVOL(2)	1dB-step	12	20	28	kohm
	RBASS		12	20	28	kohm
	RTREBLE		12	20	28	kohm
	RFADER		12	20	28	kohm
Output Noise Voltage	V _N (1)	All flat overall (I_{HFA}) $R_g=1\text{k}\Omega$		2	10	μV
	V _N (2)	0dB position (I_{HFA}) $R_g=1\text{k}\Omega$, $V_{DD}=8\text{V}$, $V_{EE}=V_{SS}=0\text{V}$		2	10	μV
Current Dissipation	I_{DD}	$V_{DD}-V_{EE}=15\text{V}$			1	mA
	I_{CC}	$V_{CC}=5\text{V}$			1	mA

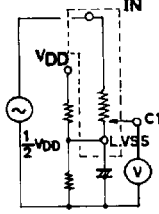

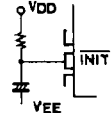
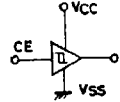
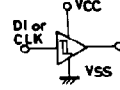
Pin Description (): LC7537AN

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Pin No.	Symbol	Description of Functions	Remarks
12(8)	L.IN	Main Volume Control Block 5dB-Step Attenuator Input Terminals. These pins should be driven at a low impedance.	
31(29)	R.IN		
9(4)	L.C1	Main Volume Control Block 5dB-Step Attenuator Output Terminals. Having been designed to be open, the step positions will develop errors if at low acceptor impedances, so that as high load impedances as possible should be provided.	VR Resistance : 20kohms
34(33)	R.C1		
10(5)	L.C2	Main Volume Control Block 1dB-Step Attenuator Input Terminals. These pins should be driven at a low impedance.	
33(32)	R.C2		
11(6)	L.OUT	Main Volume Control Block 1dB-Step Attenuator Output Terminals. Due to the step positions designed to be open, load impedances as high as possible should be provided to them, similar to those for the LC1 and RC1.	VR Resistance : 20kohms
32(31)	R.OUT		
5(47)	L.FIN	Fader Functions Employing Mode Input Terminals. These pins should be driven at a low impedance.	
38(38)	R.FIN		
4(46)	L.FOUT	Fader Block Output Terminals. These pins permit the front and rear sides to be faded out independently of each other. Attenuations exercised on Lch will be the same as on Rch. Due to the step positions designed to be open, acceptor impedances as high as possible should be provided to them.	VR Resistance : 20kohms
3(45)	L.ROUT		
39(39)	R.FOUT		
40(40)	R.ROUT		

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Pin No.	Symbol	Description of Functions	Remarks
15(11) 16(9) 14(10) 28(26) 27(28) 29(27)	L.B1 L.B2 L.B3 R.B1 R.B2 R.B3	Bass Tone Control Block Terminals. A total of 15 positions have been provided in 2dB steps.	VR Resistance : 20kohms
17(13) 16(12) 18(14) 26(24) 27(25) 25(23)	L.T1 L.T2 L.T3 R.T1 R.T2 R.T3	Treble Tone Control Block Terminals. A total of 15 positions have been provided in 2dB steps. The VR resistance value is 20kohm.	VR Resistance : 20kohms
7(1) 6(48) 36(36) 37(37)	LCT1 LCT2 RCT1 RCT2	Loudness Dedicated Terminals. A high-frequency-range correcting C should be put between CT1 and IN, and low-frequency-range-correcting C between CT2 and L.V _{SS} (R.V _{SS}).	
8(2) 35(35)	L.V _{SS} R.V _{SS}	Main Volume Control Block Fader Control Common Terminals. The impedance of pattern connected to these pins should be as low as possible. Since L.V _{SS} , R.V _{SS} , and V _{SS} have not been connected inside the LSI, they should be connected together on the outside in conformance with their individual specifications. Particular attenuation should be paid to the capacitance assigned to the capacitors put between L.V _{SS} (R.V _{SS}) and V _{SS} , which will emerge as a residual resistive component when control is turned down for maximum attenuation.	
42(42)	INIT	Intra-IC Latch Resetting Terminal  Control-setting data at the internal latch will be indeterminate when power has just been switched on, so that by engaging the "L" level of this pin at power-on, the fader control may be set at its -∞ position and muting behavior is engaged (Note: V _{DD} -V _{EE} Level).	
22(20)	CE	Chip Enable Terminal. When this pin is made "H"→"L", data is written in the internal latch, activating the various analog switches. When the "H" level is then restored, transfer of the data will be enabled.	
20(16) 21(17)	DI CLK	Input Terminals for Serial Data and Clock that serve control purposes.	

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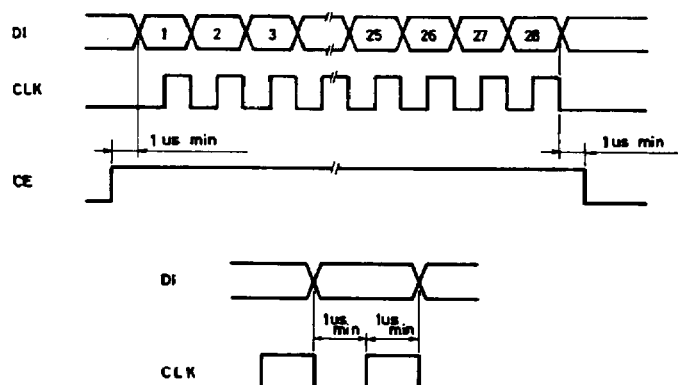
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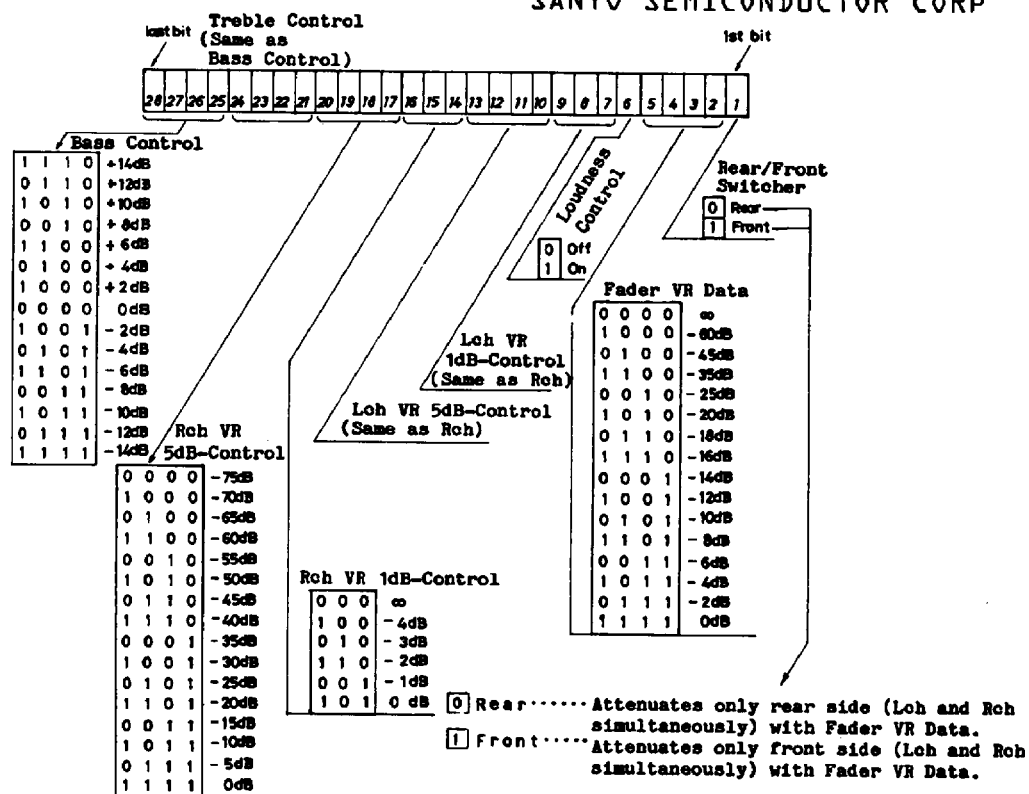
Pin No.	Symbol	Description of Functions	Remarks
1(43) 23(21) 19(15) 24(22)	V_{DD} V_{CC} V_{SS} V_{EE}	These pins are connected to the relevant power supplies. Exercise caution against V_{CC} rising earlier than V_{DD} .	
2(3,7) 41(18, 30,34, 41,44)	NC	No Connect Pins. Absolutely nothing should be connected here.	
(19)	$V_{DD}(NC)$	V_{DD} subterminal. Connected to V_{DD} or left open.	LC7537AN only

Control Timing



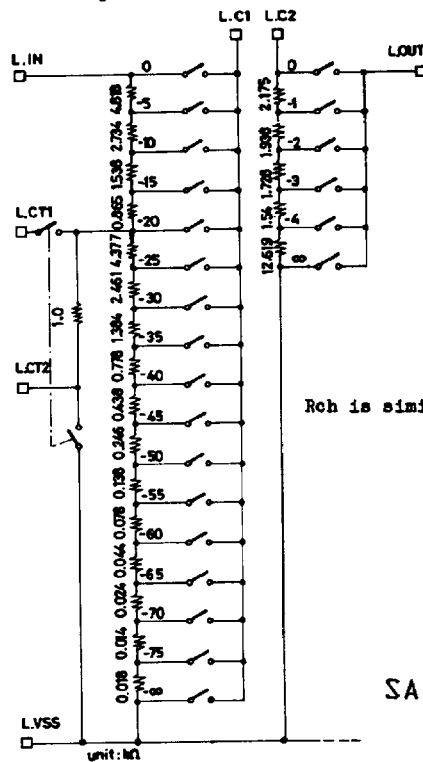
Data Format

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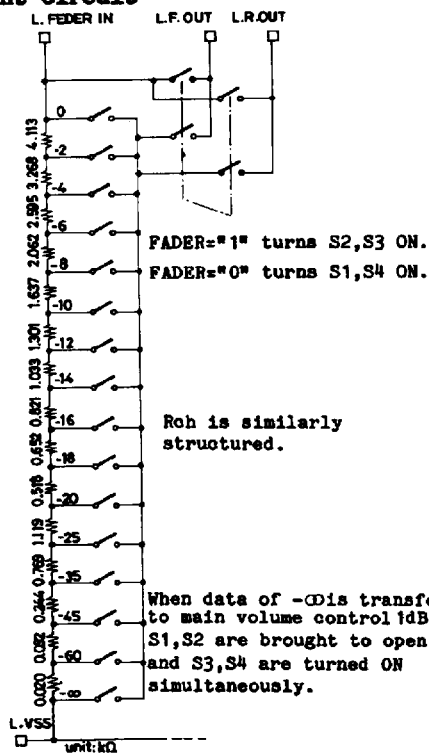
Main Volume Control Block Equivalent Circuit



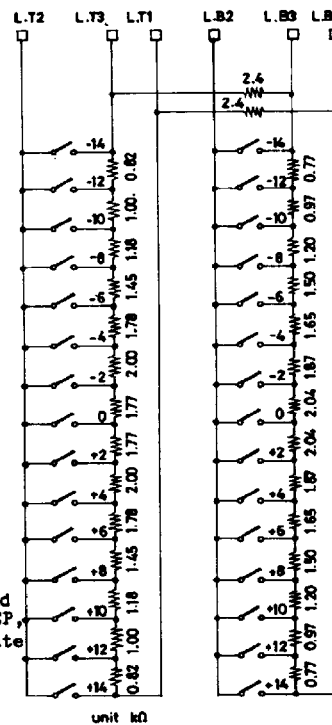
Roh is similarly structured.

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Fader Volume Control Block Equivalent Circuit

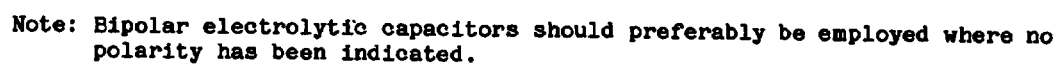


Tone Control Block Equivalent Circuit



Roh is similarly structured.

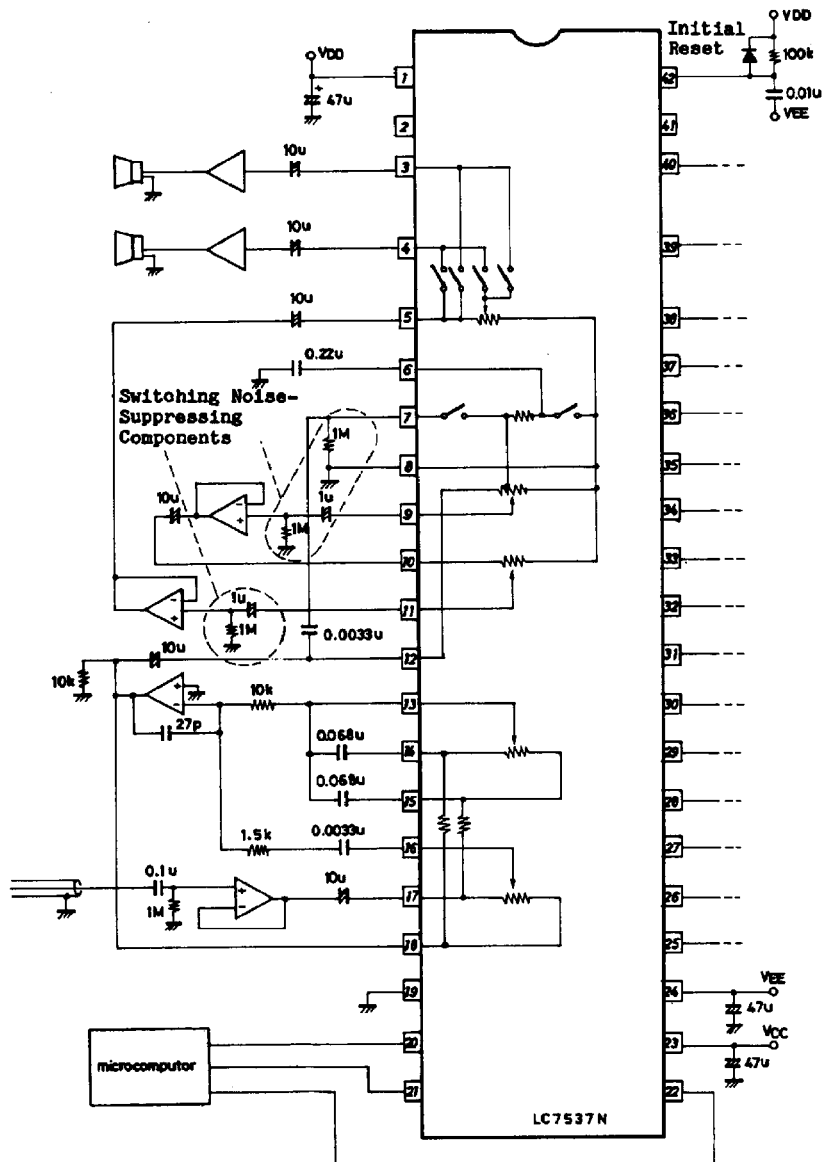
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(2) Dual \pm Power Supply

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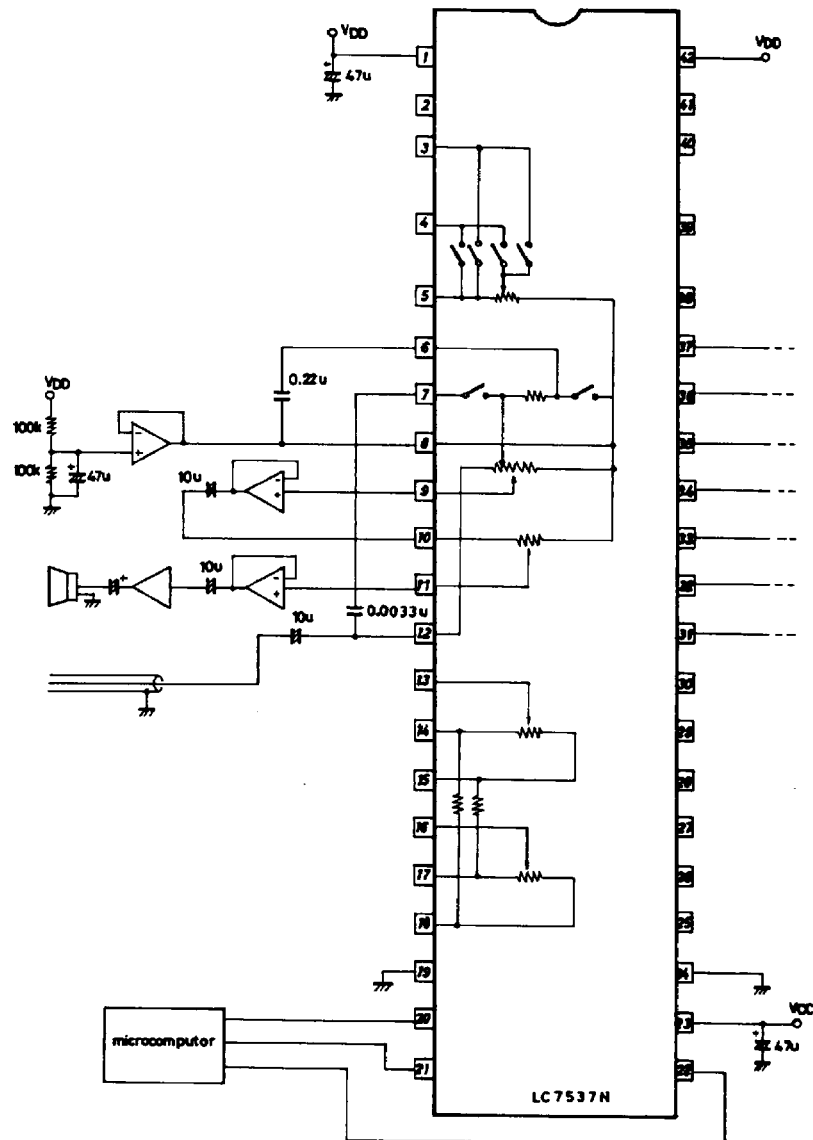


Note: Bipolar electrolytic capacitors should preferably be employed where no polarity has been indicated.

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(3) Single Power Supply

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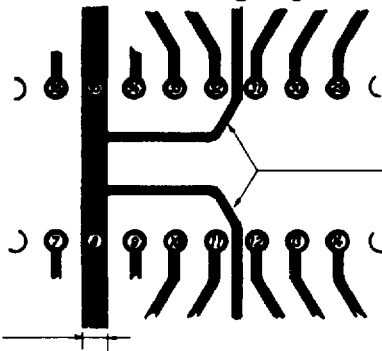


Note: Bipolar electrolytic capacitors should preferably be employed where no polarity has been indicated.

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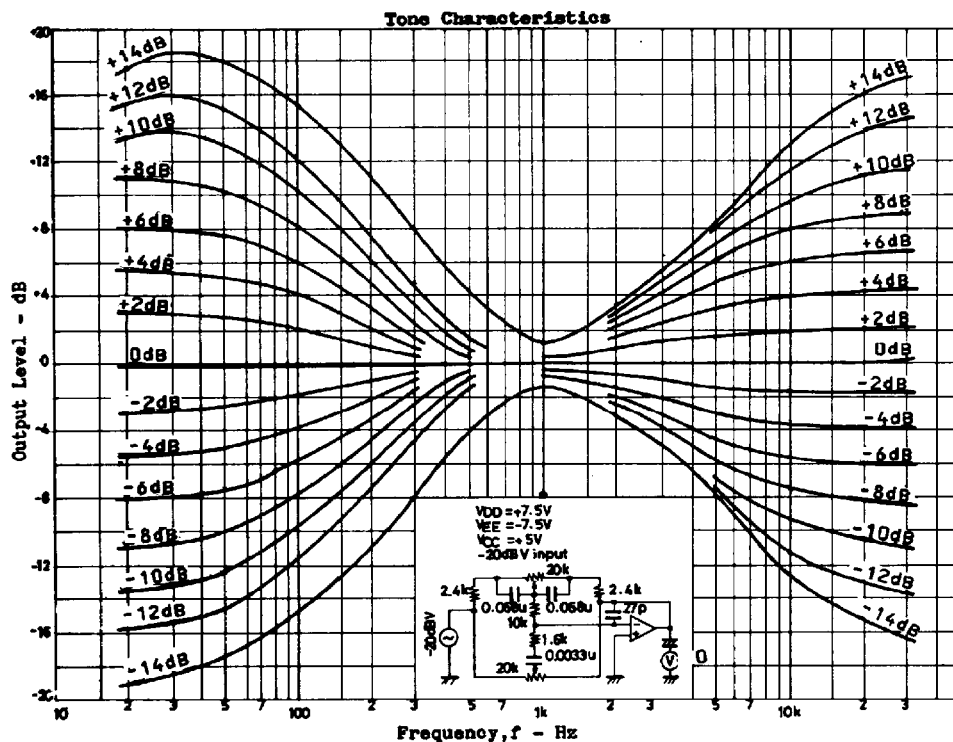
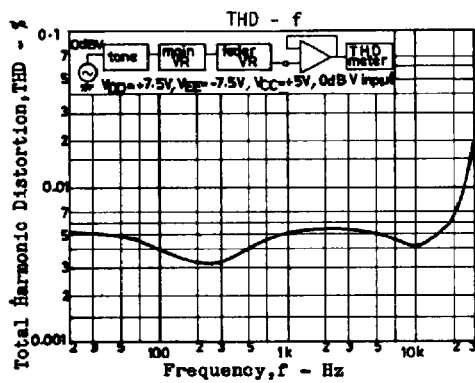
Caution for Pattern Designing

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Shielding Patterns

- Space the patterns between L.IN and L.OUT and those between R.IN and R.OUT as far apart as possible. When forced to design them close together, provide shielding patterns between as illustrated. They will be effective at the maximum attenuated level (with 10kHz and higher frequencies).(DIP42S)
- Make the L.V_{SS} and R.V_{SS} as broad as possible.



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